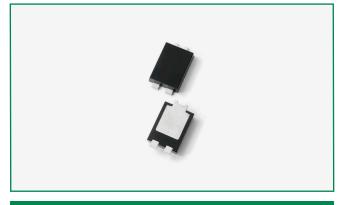
Schottky Barrier Rectifier DST1050S, 10A, 50V, TO-277B, Single

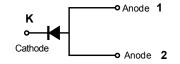
DST1050S

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Description

Littelfuse DST series Ultra Low V_F Schottky Barrier Rectifier is designed to meet the general requirements of commercial and industry applications by providing high temperature, low leakage and lower V_F products.

It is suitable for high frequency switching mode power supply, free-wheeling diodes and polarity protection diodes.

Features

- Ultra low forward voltage drop
- High frequency operation
- MSL: Level 1 unlimited
- High junction temperature capability
- Trench MOS Schottky technology
- Single die in TO-277B Package

HF Rohs 🕅 🕄

 Pb-free E3 means 2nd level interconnect is Pb-free and the terminal finish material is tin(Sn) (IPC/ JEDEC J-STD-609A.01)

Applications

- Switching mode power supply
- DC/DC converters
- Free-Wheeling diodes
- Polarity Protection Diodes

Maximum Ratings

Parameters	Symbol	Test Conditions	Max	Unit
Peak Inverse Voltage	V _{RWM}	-	50	V
Average Forward Current	I _{F(AV)}	50% duty cycle @T _L = 125 °C rectangular wave form	10	А
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse	150	А

Electrical Characteristics

Parameters	Symbol	Test Conditions	Тур	Max	Unit
Forward Voltage Drop*		@5A, Pulse, T _J = 25 °C	0.40	0.48	- V
	V _{F1}	@10A, Pulse, T _J = 25 °C	0.47	0.55	
		@5A, Pulse, T _J = 125 °C	0.30	0.39	
	V _{F2}	@10A, Pulse, T _J = 125 °C	0.40	0.49	
Reverse Current*	I _{R1}	$@V_{R} = rated V_{R} T_{J} = 25 \text{ °C}$	0.05	1.5	mA
	I _{B2}	$@V_{R} = rated V_{R} T_{I} = 125 \text{ °C}$	32	85	

* Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications				
Parameters	Symbol	Test Conditions	Max	Unit
Junction Temperature	T		-55 to +150	°C
Storage Temperature	T _{stg}		-55 to +150	°C
Maximum Thermal Resistance Junction to Ambient	R _{thJA}		75	°C/W
Maximum Thermal Resistance Junction to Lead	R _{thJL}	DC operation	3.5	°C/W
Approximate Weight	wt		0.08	g
Case Style	ТО-277В			

Figure 1: Typical Forward Characteristics

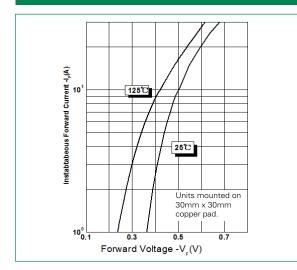


Figure 3: Typical Junction Capacitance

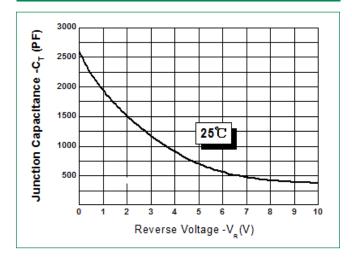
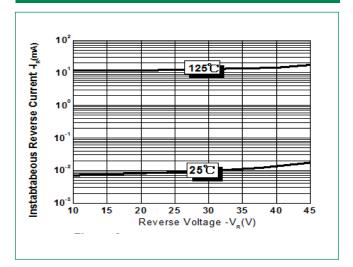
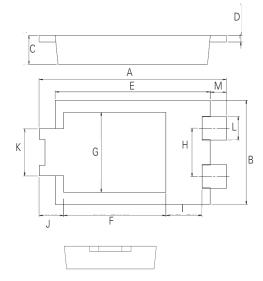


Figure 2: Typical Reverse Characteristics

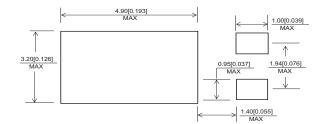




Dimensions-TO-277B



Mounting Pad Layout



Symbol	Millimeters			
Symbol	Min	Тур	Max	
Α	6.30	6.50	6.70	
В	3.88	3.98	4.08	
С	0.95	1.10	1.25	
D	0.20	0.25	0.30	
E	5.28	5.38	5.48	
F	3.40	3.55	3.70	
G	2.90	3.05	3.20	
Н	1.74	1.84	1.94	
I	1.10	1.25	1.40	
J	-	0.85	-	
К	1.70	1.80	1.90	
L	0.85	0.90	0.95	
М	-	0.56	-	

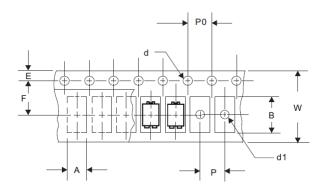
Part Numbering and Marking System

DST1050S	DST 10 50
05110505	S
LF YYWWL	LF YY
	WW
	L

- = Device Type = Forward Current (10A)
- = Reverse Voltage (50V) = Package Type = Littelfuse
- = Year
- = Week
- = Lot Number

Packing Options					
Part Number	Marking	Packing Mode	M.O.Q		
DST1050S	DST1050S	5000pcs / Reel	5000		

Carrier Tape & Reel Specification



Symbol	Millimeters			
Symbol	Min	Max		
Α	4.28	4.48		
В	6.80	7.00		
d	1.40	1.60		
d1	-	1.50		
E	1.65	1.85		
F	5.40	5.60		
Р	7.90	8.10		
P0	3.90	4.10		
w	11.70	12.30		

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